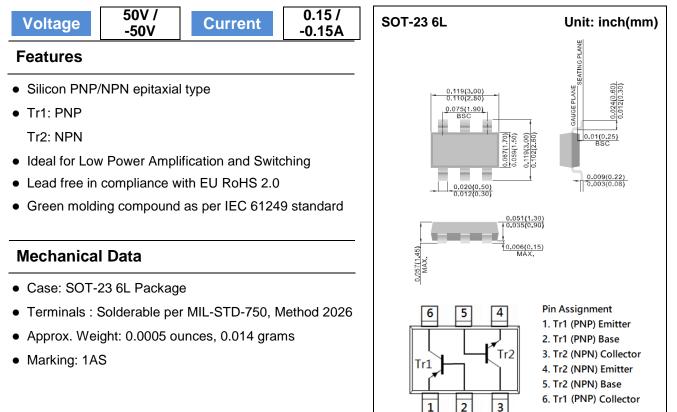
| ΡΛΝ | JIT       |
|-----|-----------|
|     | SEMI      |
|     | CONDUCTOR |

#### **Complementary Dual General Purpose Transistor**



#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER  | SYMBOL                           | Tr1     | Tr2  | UNITS |
|--|----------------------------------|---------|------|-------|
| Collector-Base Voltage                                     | V <sub>CBO</sub>                 | 50      | -50  |       |
| Collector-Emitter Voltage                                  | V <sub>CEO</sub>                 | 60      | -60  | V     |
| Emitter-Base Voltage                                       | V <sub>EBO</sub>                 | 7       | -6   |       |
| Collector Current (DC)                                     | Ι <sub>C</sub>                   | 150     | -150 | mA    |
| Total Power Dissipation                                    | P <sub>D</sub>                   | 300     |      | mW    |
| Operating Junction and Storage Temperature Range           | T <sub>J</sub> ,T <sub>STG</sub> | -55~150 |      | °C    |
| Typical Thermal Resistance from Junction to Ambient (Note) | $R_{	extsf{	heta}JA}$            | 100     |      | °C/W  |

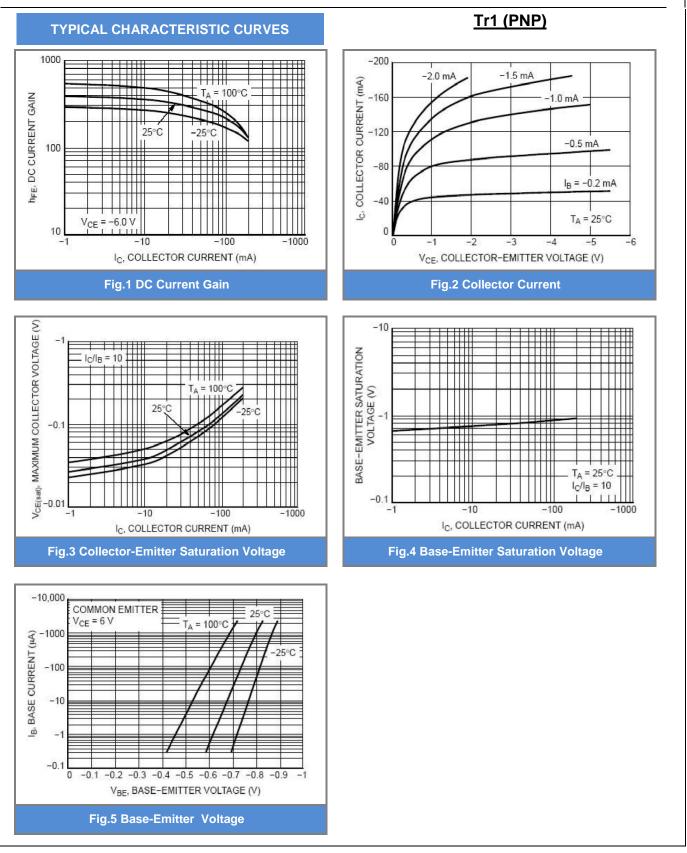
Note: Mounted on FR4 with 2oz. PCB at 1 inch square copper pad.



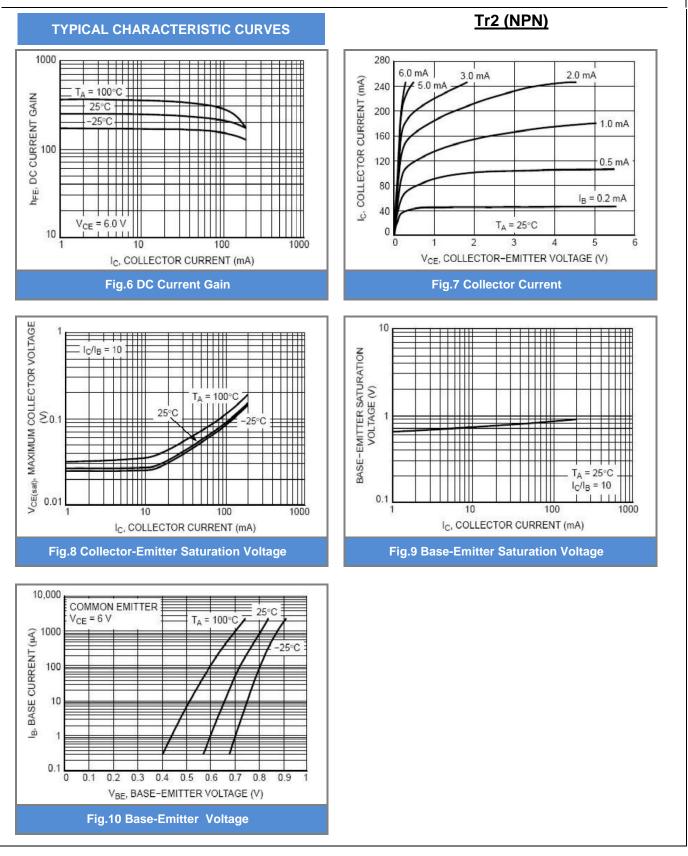
| <b>Electrical Characteristics</b> | $(T_A=25^{\circ}C \text{ unless otherwise noted})$ |
|-----------------------------------|--|
|-----------------------------------|--|

| PARAMETER   | SYMBOL               | TEST CONDITION   | MIN. | TYP. | MAX. | UNITS |  |
|---|----------------------|--|------|------|------|-------|--|
| Tr1 (PNP)   |                      |  |      |      |      |       |  |
| OFF Characteristics                                     |                      |  |      |      |      |       |  |
| Collector-Emitter Breakdown Voltage                     | BV <sub>CEO</sub>    | I <sub>C</sub> = -1mA, I <sub>B</sub> = 0A                                 | -50  | -    | -    |       |  |
| Collector-Base Breakdown Voltage                        | BV <sub>CBO</sub>    | I <sub>C</sub> = -50uA, I <sub>E</sub> = 0A                                | -60  | -    | -    | V     |  |
| Emitter-Base Breakdown Voltage                          | BV <sub>EBO</sub>    | I <sub>E</sub> = -50uA, I <sub>C</sub> = 0A                                | -6   | -    | -    |       |  |
| Collector-Base Cutoff Current                           | I <sub>CBO</sub>     | $V_{CB}$ = -60V, I <sub>E</sub> = 0A                                       | -    | -    | -100 |       |  |
| Emitter-Base Cutoff Current                             | I <sub>EBO</sub>     | V <sub>EB</sub> = -6V  | -    | -    | -100 | nA    |  |
| ON characteristics                                      | •                    |  |      | •    |      |       |  |
| DC Current Gain   | h <sub>FE</sub>      | $V_{CE}$ = -6V $I_{C}$ = -1mA  | 120  | -    | 560  | -     |  |
| Collector-Emitter Saturation Voltage                    | V <sub>CE(SAT)</sub> | I <sub>C</sub> = -50mA, I <sub>B</sub> = -5mA                              | -    | -150 | -500 | mV    |  |
| Transition Frequency                                    | f <sub>T</sub>       | I <sub>E</sub> = -2mA, V <sub>CE</sub> = -12V<br>f=100MHz                  | -    | 140  | -    | MHz   |  |
| Collector Output Capacitance                            | C <sub>OB</sub>      | V <sub>CB</sub> = -12V I <sub>E</sub> = 0A,<br>f=100MHz                    | -    | 4    | 5    | pF    |  |
| Tr2 (NPN)<br>OFF Characteristics                        |                      |  |      |      |      | -     |  |
| Collector-Emitter Breakdown Voltage                     | BV <sub>CEO</sub>    | $I_{C}$ = 1mA, $I_{B}$ = 0A  | 50   | -    | -    |       |  |
| Collector-Base Breakdown Voltage                        | BV <sub>CBO</sub>    | I <sub>C</sub> = 50uA, I <sub>E</sub> = 0A                                 | 60   | -    | -    | V     |  |
| Emitter-Base Breakdown Voltage                          | BV <sub>EBO</sub>    | I <sub>E</sub> = 50uA, I <sub>C</sub> = 0A                                 | 7    | -    | -    | -     |  |
| Collector-Base Cutoff Current                           | I <sub>CBO</sub>     | $V_{CB} = 60V, I_E = 0A$   | -    | -    | 100  |       |  |
| Emitter-Base Cutoff Current                             | I <sub>EBO</sub>     | V <sub>EB</sub> = 7V   | -    | -    | 100  | nA    |  |
| ON characteristics                                      |                      |  |      |      |      |       |  |
|   | h <sub>FE</sub>      | $V_{CE}$ = 6V $I_{C}$ = 1mA  | 120  | -    | 560  | -     |  |
| DC Current Gain   |                      |  | -    | 100  | 400  | mV    |  |
| DC Current Gain<br>Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub> | $I_{C}$ = 50mA, $I_{B}$ = 5mA  |      |      |      |       |  |
|   | V <sub>CE(SAT)</sub> | $I_{c}$ = 50mA, $I_{B}$ = 5mA<br>$I_{E}$ = 2mA, $V_{CE}$ = 12V<br>f=100MHz | -    | 180  | -    | MHz   |  |







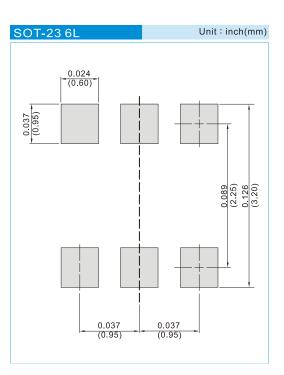




#### Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type     | Marking | Version      |
|----------------------|--------------|------------------|---------|--------------|
| IMZ1AS_S1_00001      | SOT-23 6L    | 3K pcs / 7" reel | 1AS     | Halogen free |

#### **Mounting Pad Layout**





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